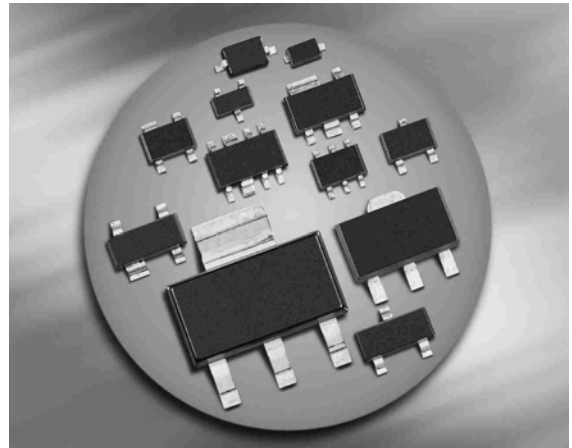
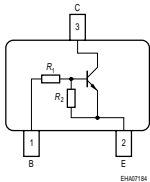
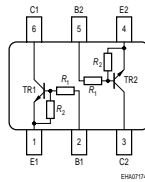


NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=2.2k\Omega$, $R_2=2.2k\Omega$)
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package


BCR103/F
BCR103L3/T

BCR103U


Type	Marking	Pin Configuration						Package
BCR103	WAs	1=B	2=E	3=C	-	-	-	SOT23
BCR103F	WAs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR103L3	WA	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR103T	WAs	1=B	2=E	3=C	-	-	-	SC75
BCR103U	WAs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SC74

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	5	
Input on voltage	$V_{i(on)}$	10	
Collector current	I_C	100	mA
Total power dissipation- BCR103, $T_S \leq 102^\circ\text{C}$ BCR103F, $T_S \leq 128^\circ\text{C}$ BCR103L3, $T_S \leq 135^\circ\text{C}$ BCR103T, $T_S \leq 109^\circ\text{C}$ BCR103U, $T_S \leq 118^\circ\text{C}$	P_{tot}	200 250 250 250 250	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BCR103		≤ 240	
BCR103F		≤ 90	
BCR103L3		≤ 60	
BCR103T		≤ 165	
BCR103U		≤ 133	

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

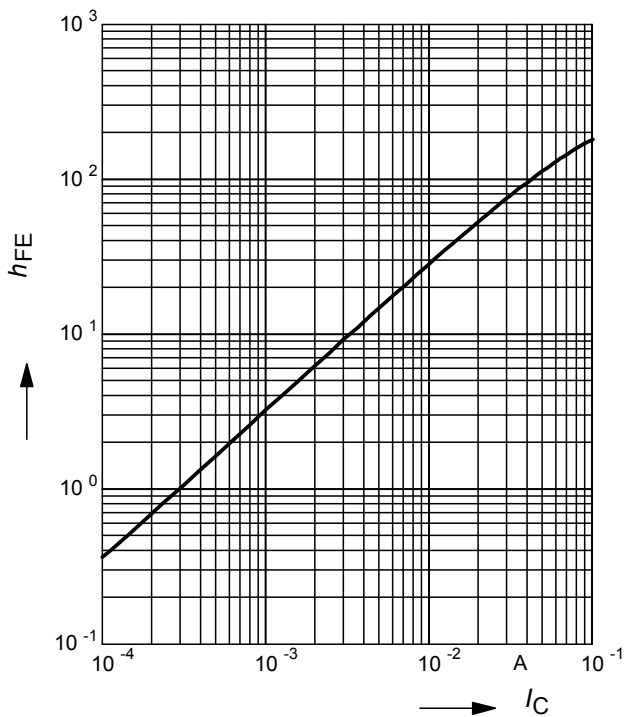
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$	I_{EBO}	-	-	3.5	mA
DC current gain ¹⁾ $I_C = 20 \text{ mA}, V_{CE} = 5 \text{ V}$	h_{FE}	20	-	-	-
Collector-emitter saturation voltage ¹⁾ $I_C = 20 \text{ mA}, I_B = 1 \text{ mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(off)}$	0.8	-	1.5	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$	$V_{i(on)}$	0.8	-	2.5	
Input resistor	R_1	1.5	2.2	2.9	k Ω
Resistor ratio	R_1/R_2	0.9	1	1.1	-
AC Characteristics					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$	f_T	-	140	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{cb}	-	3	-	pF

¹Pulse test: $t < 300 \mu\text{s}$; $D < 2\%$

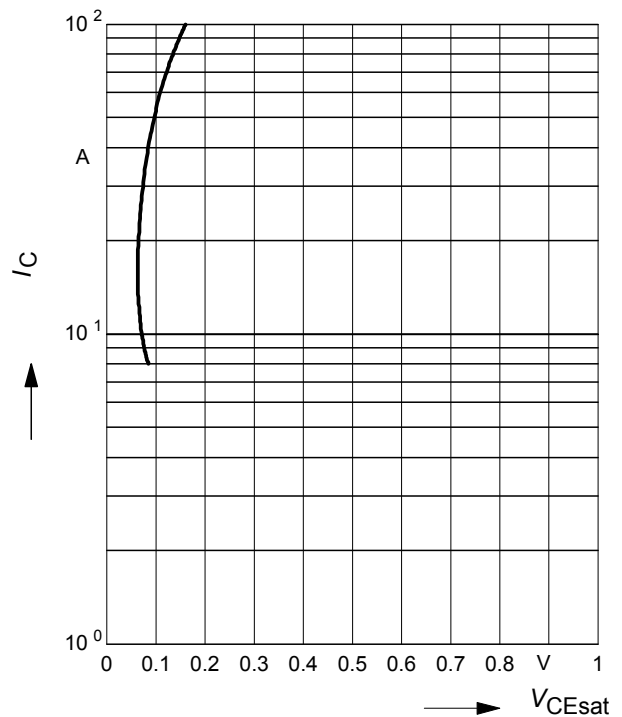
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



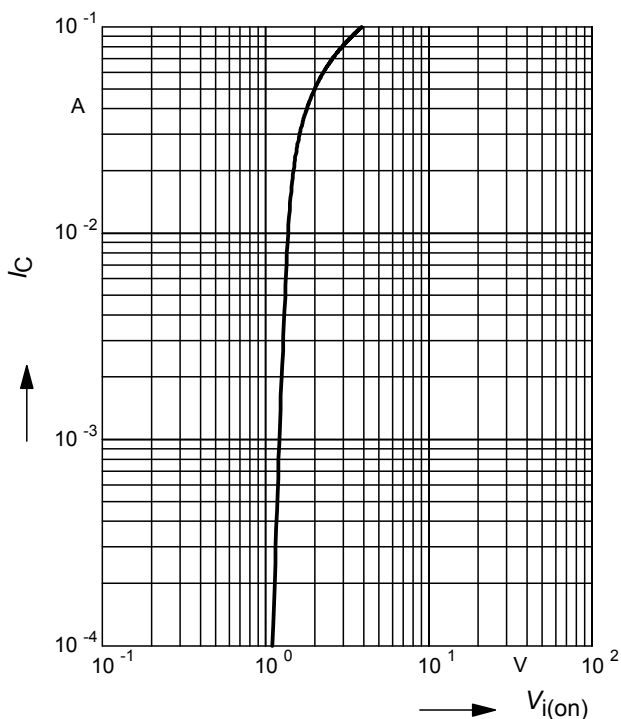
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



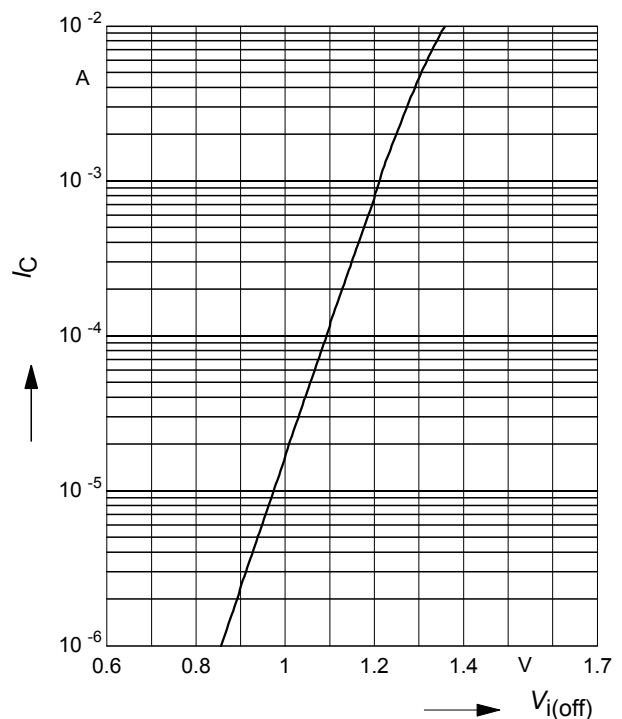
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3V$ (common emitter configuration)



Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



Total power dissipation $P_{tot} = f(T_S)$

BCR103



Total power dissipation $P_{tot} = f(T_S)$

BCR103F



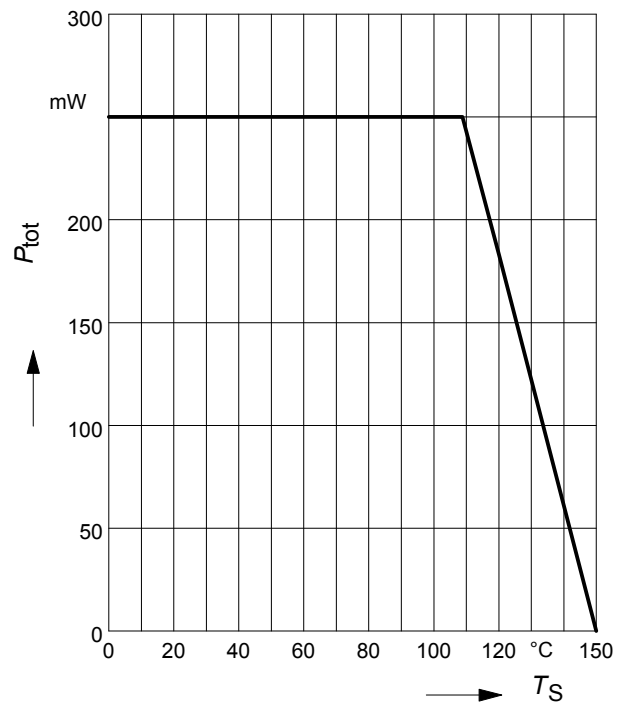
Total power dissipation $P_{tot} = f(T_S)$

BCR103L3



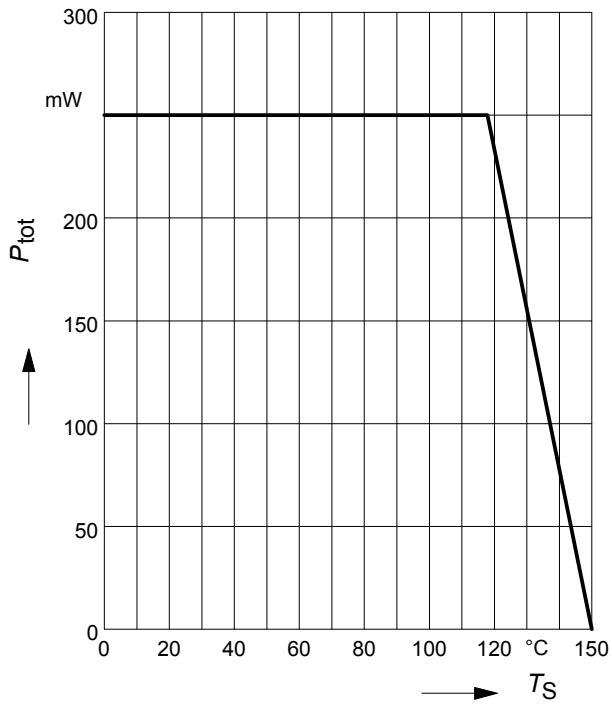
Total power dissipation $P_{tot} = f(T_S)$

BCR103T



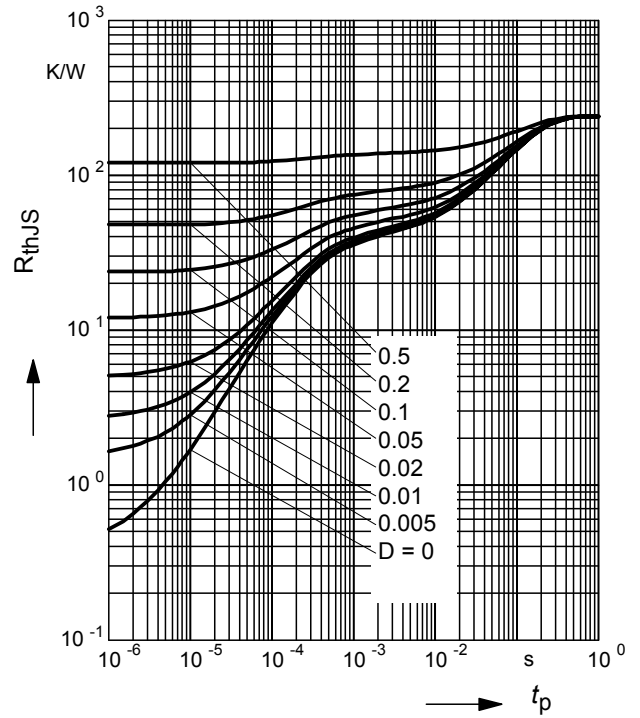
Total power dissipation $P_{tot} = f(T_S)$

BCR103U



Permissible Pulse Load $R_{thJS} = f(t_p)$

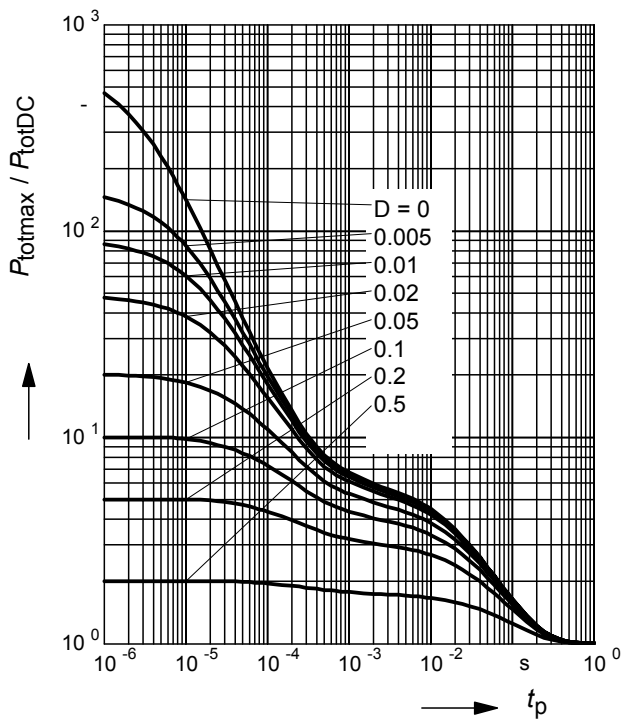
BCR103



Permissible Pulse Load

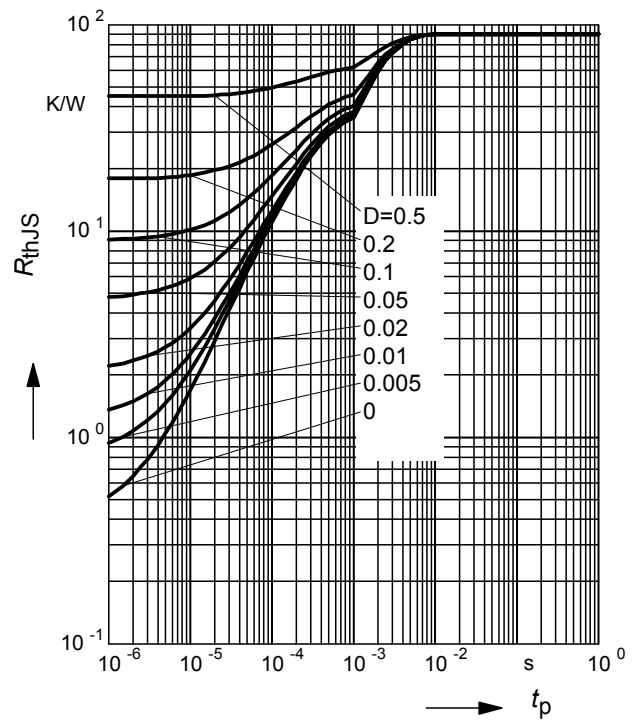
$P_{totmax}/P_{totDC} = f(t_p)$

BCR103



Permissible Puls Load $R_{thJS} = f(t_p)$

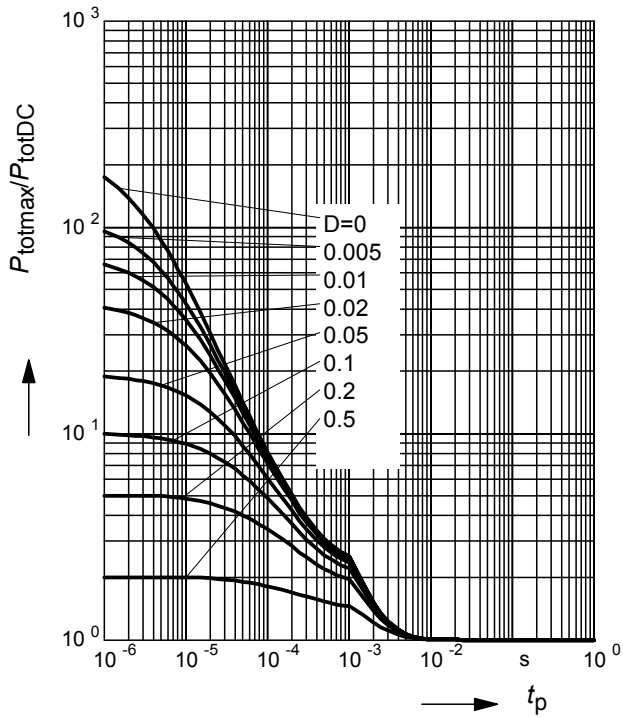
BCR103F



Permissible Pulse Load

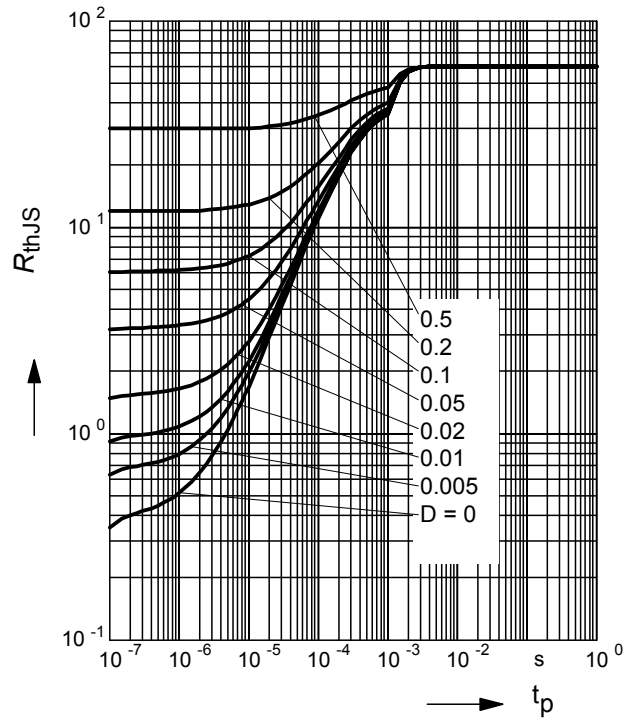
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103F



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

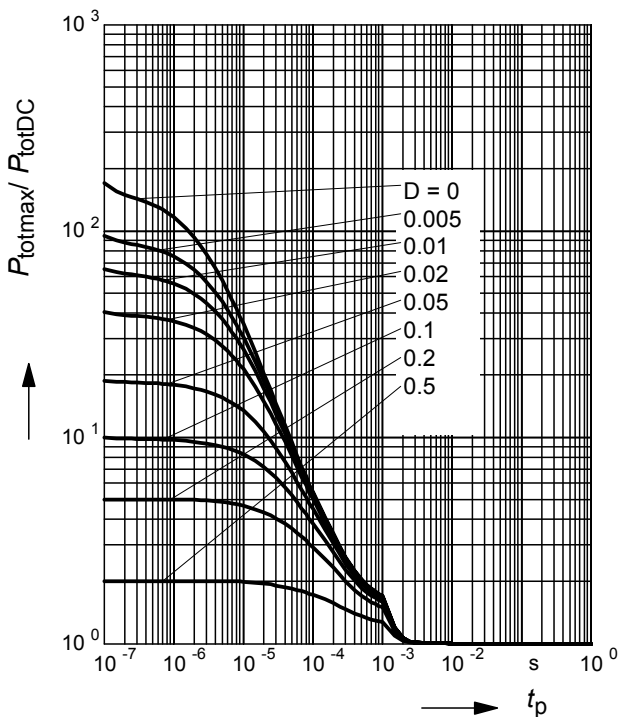
BCR103L3



Permissible Pulse Load

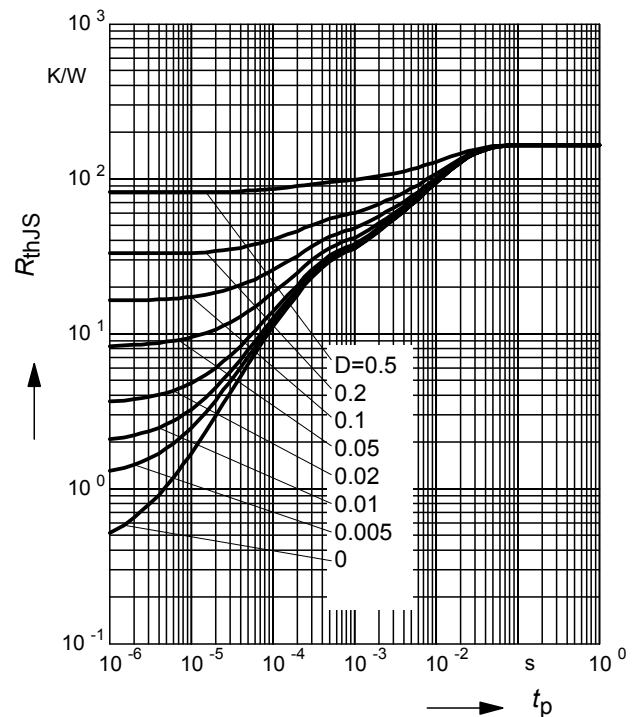
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103L3



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

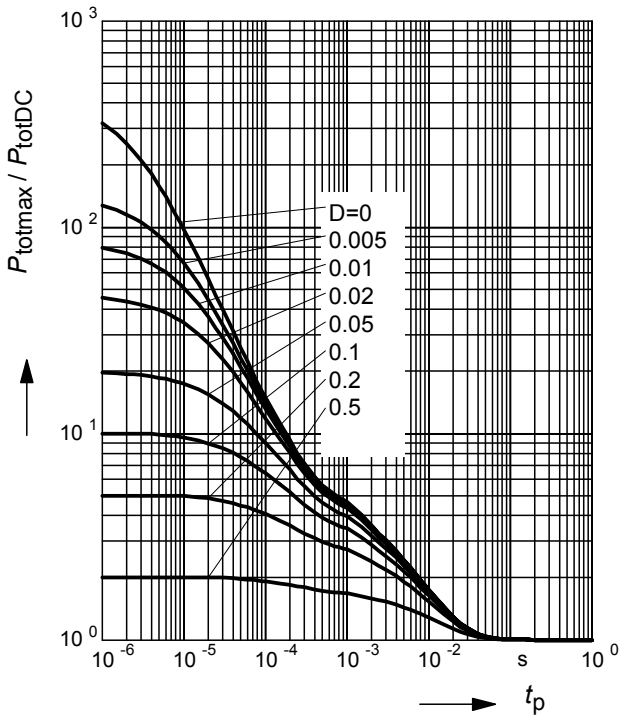
BCR103T



Permissible Pulse Load

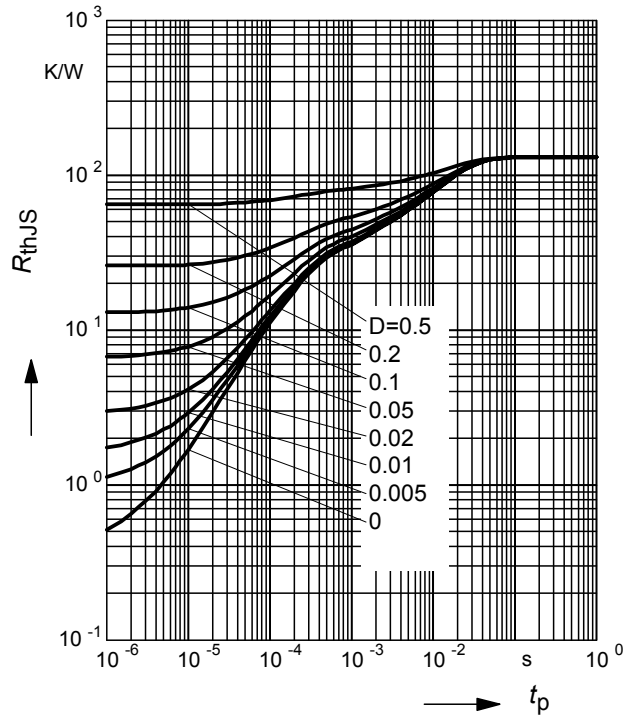
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103T



Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

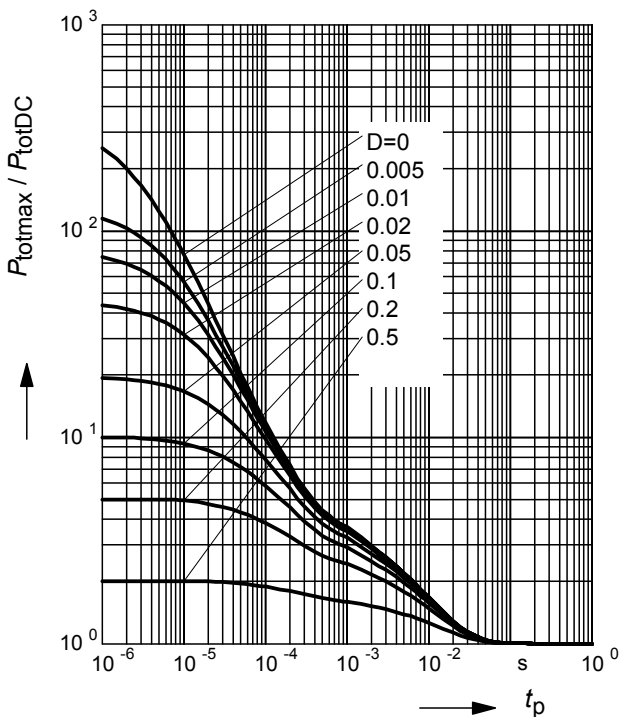
BCR103U



Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR103U



This datasheet has been downloaded from:

www.DatasheetCatalog.com

Datasheets for electronic components.



LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.